BL GALAXY ELECTRICAL

SB220 --- SB260

SCHOTTKY BARRIER RECTIFIERS

VOLTAGE RANGE: 20 --- 60V
CURRENT: 2.0 A

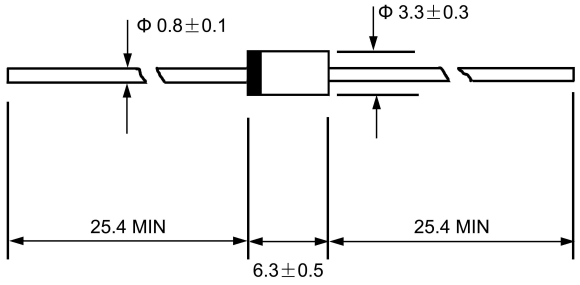
FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop,low switching losses
- ◇ High surge capability
- ◇ For use in low voltage,high frequency inverters free wheeling,and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case:JEDEC DO--15,molded plastic
- ◇ Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces,0.39 grams
- ◇ Mounting position: Any

DO - 15



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		SB220	SB230	SB240	SB250	SB260	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	50	60	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	V
Maximum average forw ard rectified current 9.5mm lead length, @T_A=75℃	$I_{F(AV)}$	2.0					A
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load @T_J=125℃	I_{FSM}	50.0					A
Maximum instantaneous forw ard voltage @ 2.0A (Note1)	V_F	0.55			0.70		V
Maximum reverse current @T_A=25℃	I_R	0.5					mA
at rated DC blocking voltage @T_A=100℃		20.0					
Typical junction capacitance (Note2)	C_J	170					pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	35					℃/W
Operating junction temperature range	T_J	- 55 ---- + 125					℃
Storage temperature range	T_{STG}	- 55 ---- + 150					℃

Note: 1. Pulse test : 300μs pulse width,1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3.Thermal resistance junction to ambient.

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FIG.1 -- FORWARD CURRENT DERATING CURVE

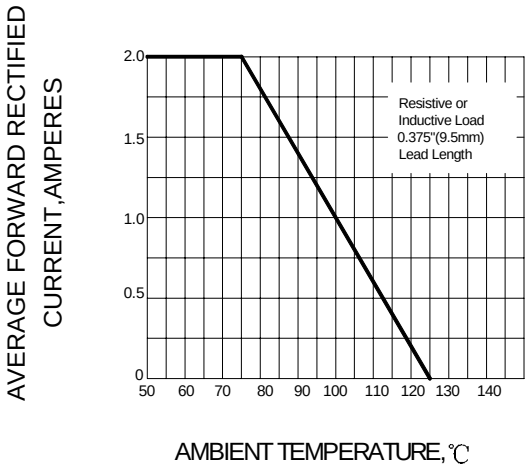

FIG.2 --TYPICAL INSTATANEOUS FORWARD CHARACTERISTICS

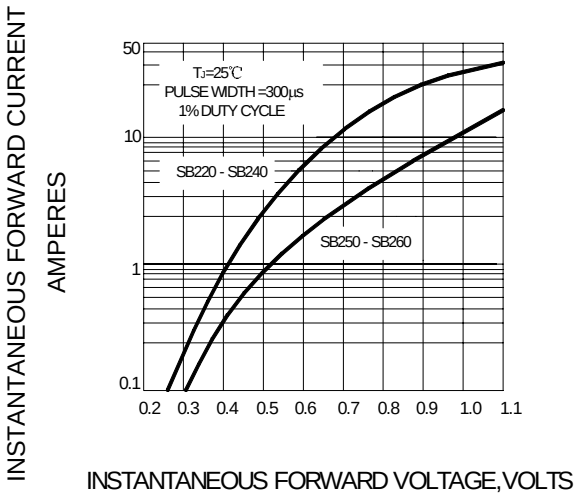

FIG.3 --TYPICAL REVERSE CHARACTERISTICS

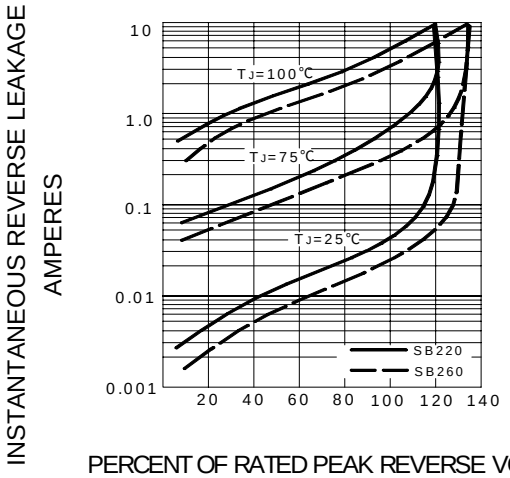

FIG.4--MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

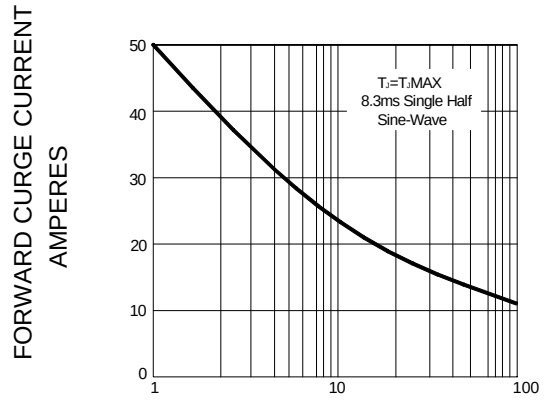

FIG.5--TYPICAL JUNCTION CAPACITANCE